





Global Presence

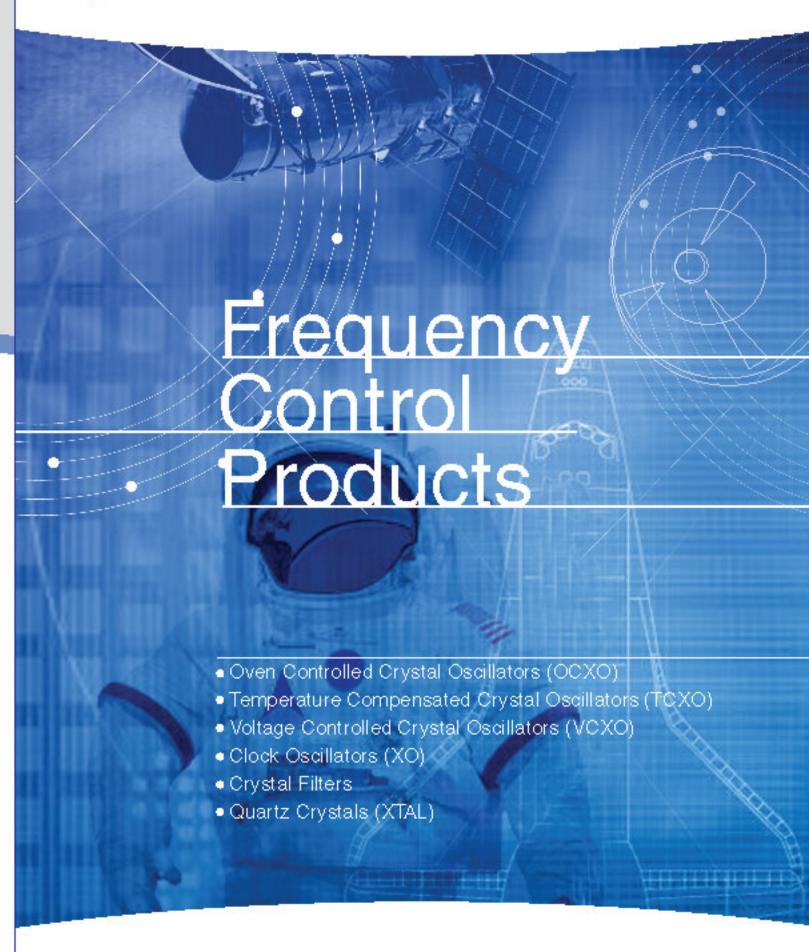




AA, KIIB Industria, Area, Yelahan ka New Town Bangalore – 580 108 - India Tel: +91 80 300 A8000 Fax: +91 80 300 A8005 Email: sales≪xientumelectronics.com



SPACE



INTRODUCTION

Centum Rakon is a joint venture between Centum Electronics Ltd Bangalore, India and Rakon Ltd, New Zealand. Two world class companies providing the design and manufacturing of high performance crystals and crystal oscillators including XO, VCXO, TCXO and OCXO's globally. Centum Rakon provides products to the Space, Defence, Aerospace, Communications and Mobile markets.

- Leader in the design and manufacturing of crystals and crystal oscillators including XO,VCXO,TCXO and OCXO.
- One of the largest design and manufacturing company for OCXO's in the world
- World class manufacturing processes including quartz crystal processing.
- High quality custom built products processes conforming to MIL-PRF-38534, MIL-STD-883E,MIL-PRF-55310, ISRO-PAX 300,ISO 9001-2008, ISO-14000 standards

VISION

To Create Value by contributing to the Success of its Customers, by providing best-in-class Electronics Design and Manufacturing Solutions in high technology areas

QUALITY POLICY



'All our products and services shall meet the expectations of our customers and stake-holders in quality, technology and value. This commitment is achieved through effective teamwork of every employee, supplier and customer.

We shall develop, maintain and continually improve a documented system and enhance quality of all our products, processes and services and promote customer trust and satisfaction".

HERITAGE

- Hi-Rel products conforming to the most stringent Space standards for prestigious projects like INSAT/GSAT series, IRS series, Chandrayaan, MARS Mission.
- Approved by ISRO centers like SAC, VSSC and ISAC for payload, launch vehicles & other satellite applications.



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COMPLETE FCP OFFERING



Crystals

Wide range of standard and custom solutions





XO

High frequency, low jitter performance



CVX3520S



CTX3825S

performano

eme

EX.

CTX3520S

VCXO

High frequency, low jitter performance

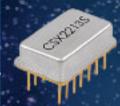


Up to ±1.0ppm over wide temperature ranges in high volume



Broad product range





PACKAGE 22×13×5m m FREQUENCY RANGE 0.160 to 100.0MHz

STABILITY -55 to +125°C ±50ppm Other custom regirements are also available.

SUPPLY VOLTAGE +5.0V_jupto 15.0Volts **OUTPUT TYPE** HCMOS, ACMOS, TTL, Sine

FEATURES Low jitter, Wide fequency range

XO

CSX2521S



PACKAGE 25.4/21x10mm FREQUENCY RANGE 0.160 to 250,0MHz

STABILITY -55 to +125°C ±60ppm Other custom regirements are also available.

SUPPLY VOLTAGE +5.0V,upto 15.0Volts **OUTPUT TYPE** HCMOS, ACMOS, TTL, Sine, ECL

FEATURES Lowjitter, Wide fequency range

CVX3520S



PACKAGE 34.5X20.19X10mm FREQUENCY RANGE 0.160 to 100.0MHz

INPUT VOLTAGE +3:2V;+5:0V;upto 15:0Volts

PULLING RANGE ±30 to ±100ppm OUTPUTTYPE SNE

FRENQUENCY STABILITY

VCXO

0 to 50°C ±10ppm 0 to 70°C ±10ppm -10 to 70°C ±10ppm -20 to 70°C ±20ppm -40 to 95°C ±30ppm

CTX3520S



PACKAGE. 35X20X15mm FREQUENCY RANGE 5.0-375.0MHz

STÄBILITY -10 to 60°C ±1 .0ppm -20 to 70°C ±2.0ppm Other custom requirements are also available

SUPPLY VOLTAGE +5.0V₁+9.0V₁12.0V₁ 15.0Volts OUTPUT TYPE HCMOS, ACMOS, TTL, Sine

TCXO

FEATURES* Excelent phase noise, Requency select option, Low jtter, Wide frequency range

CTX3825S



PACKAGE 38.2x25.6x7mm FREQUENCY RANGE 5.0-375.0MHz

STABILITY -10 to 60°C ±1 0ppm -20 to 70°C ±2.0ppm Other custom requirements are also available

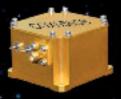
SUPPLY VOLTAGE +5.0V₁+9.0V₁12.0V₁ 15.0\bits OUTPUTTYPE HCMOS, ACMOS,

TTL, Sine

FEATURES

Excellent phase noise, Requency select option, Low jitter, Wide frequency range

COX5555S



PACKAGE 55X55X35mm FREQUENCY RANGE UPTO 130MHz

STABILITY -10 to 60°C ±10ppb Other custom requirements are also available

SUPPLY VOLTAGE +9.0V, 12.0V and 15.0V OUTPUT TYPE Sine

ocxo

FEATURES Excellent phase noise, Requency select option, Low jitter, Wide frequency range

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CRYSTAL FILTERS

Frequency range: 5MHz to 250MHz

Bandwidth: 0.001% to 1%

High selectivity

Insertion Loss: 2 to 8 dB

2 to 8 poles

Shape factor (60dB/3dB): 1.2 min

Out-of-band rejection: 100 dB max

Temperature Range: -45°C to +90°C

Space: -10 c to +60 C

HYBRID MICRO CIRCUIT MANUFACTURING FACILITY



WORLD CLASS PRODUCTION AND TEST

- Class 1000 and 100K clean room for crystals and oscillator manufacturing
- Dedicated line and people for handing space grade products
- Dedicated simulation software for crystals and oscillator designs
- · In house substrate manufacturing capability using very latest techniques
- · In house chip and wire bonding facility using very latest techniques
- · Complete testing facility including temperature test chamber
- High end phase noise setup(cross correlation method)
- Complete screening facility including vibration & Thermo Vacuum
- Space grade approved Single, Double sided & Multilayer Thick film process, it includes printing firing & Resistor Trimming
- · Space Grade approved & MIL Certified Established Manual Soldering Process

CRYSTAL MANUFACTURING PROCESS



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SCREENING OPTIONS

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Operation	Requirements &	Class S	Class B	Engineering Model	
Operation	Conditions	(MIL-PRF-55310 Product level S)	(MIL-PRF-55310 Product level B)		
Non-Destruct Bond Pull	MIL-STD-883, Meth 2023	√	NA	NA	
Internal Visual	MIL-STD-883, Meth 2017, Class K, Meth 2032, Class K	√	√	√	
Stabilization (Vacuum) Bake	MIL-STD-883, Meth 1008 Cond C, 150° C,	48 hours min	24 hours min	if required	
Thermal Shock	MIL-STD-883, Meth 1011, Cond A	√	NA	NA	
Temperature Cycle	MIL-STD-883, Meth 1010, Cond B, 10 cycles	√	√	✓	
Constant Acceleration	MIL-STD-883, Meth 2001, Cond A, Y1 Plane only, 5000 g's	✓	√	NA	
Seal:Fine Leak	MIL-STD-883, Meth 1014,Cond A2	√	√	√	
Seal- Gross Leak	MIL-STD-202, Meth 112, Cond D	√	√	√	
Particle Impact Noise Detection(PIND)	MIL-STD-883, Meth 2020, Cond B	√	NA	NA	
Electrical Testing, Pre Burn-In					
Input Current-power	MIL-PRF-55310, Par. 4.8.5	√	NA	NA	
Output waveform	MIL-PRF-55310, Par. 4.8.20	√	NA	NA	
Output voltage-power	MIL-PRF-55310, Par. 4.8.21	√	NA	NA	
As specified	Customer PO	Customer PO	Customer PO	Customer PO	
Burn-In(Ioad)	+125°C,nominal supply voltage and burn-in-load	240 hours minimum	160 hours minimum	NA	
Electrical Testing, Pre Burn-In	Nominal and extreme supply voltages,specified load, +23°C and temperature extremes				
Input Current-power	MIL-PRF-55310, Par. 4.8.5	√	√	√	
Output waveform	MIL-PRF-55310, Par. 4.8.20				
Output voltage-power	MIL-PRF-55310, Par. 4.8.21				
As specified	Customer PO	Note:	Meta-re		
Radiographic Inspection	MIL-STD-883, Meth 2012	√	NA	NA	

TEST CAPABILITIES

1	MIL-STD-202		MIL-STD-883	
In-House Testing	Method	Test Cond	Method	Test Cond
Temperture Cycling	102	С	1010	A,B,C
Humidity	103	A,B		
Moisture Resistance	106		1004	
Thermal Shock	107	All	1011	All
Life	108	A,B,C,D	1005	
Seal	112	All	1014	A,C
Vibration,Sine	204	All		A,B,C
Vibration,Random	214	All	2007	
Radiographic(Real Time)	209		2012	A,B,C,D,E,F
Acceleration	212	A,B,C	2001	
Shock	213	All	2002	A,B
PIND			2020	
Resistance to Soldering Heat	210	B,C		
Aging at Room Temperature				
Aging at Elevated Temperature				
Die Shear Testing			2019	
Terminal Strength	211	A,B,C		
Phase Noise Under Vibration				
g Sensitivity				
Wirebond Pull Testing			2023, 2011	
DPA				
Outside Testing				
XRF(no Pure Tin)				
Radiation				
Pyrotechnic Shock(SRS)				
Class S/K Element Evaluation				

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ENVIRONMENTAL STRESS SCREENING (ESS) FACILITY





NOTES	

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